

**MSASC75W45F**  
**MSASC75W45FR**

**Features**

- Platinum schottky barrier
- Oxide passivated structure for low leakage currents
- Guard ring protection for increased reverse energy capability
- Epitaxial structure minimizes forward voltage drop
- Hermetically sealed, low profile ceramic surface mount power package
- Low package inductance
- Very low thermal resistance
- Available as standard polarity (strap is anode: MSASC75W45F) and reverse polarity (strap is cathode: MSASC75W45FR)
- TXV-level (MSASC75W45FV) and S-level (MSASC75W45FS) screening i.a.w. Microsemi Internal Procedure PS11.50 are available

**45 Volts**  
**75 Amps**

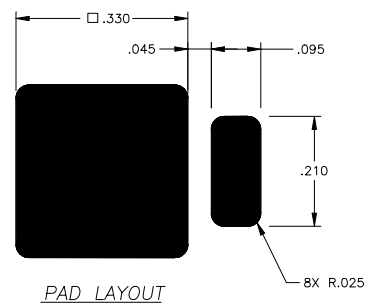
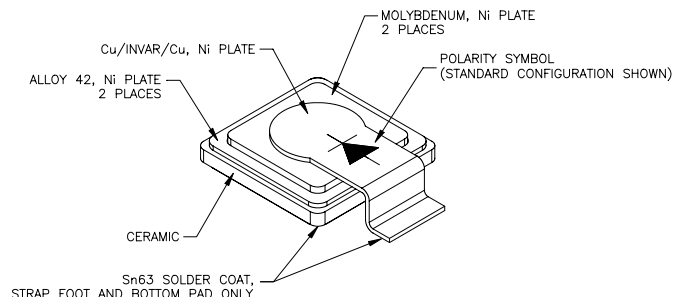
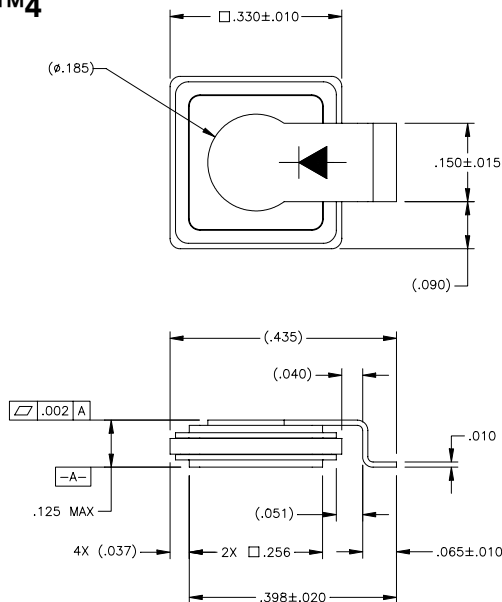
**LOW LEAKAGE**  
**CURRENT**  
**SCHOTTKY DIODE**

**Maximum Ratings @ 25°C (unless otherwise specified)**

DESCRIPTION	SYMBOL	MAX.	UNIT
Peak Repetitive Reverse Voltage	$V_{RRM}$	45	Volts
Working Peak Reverse Voltage	$V_{RWM}$	45	Volts
DC Blocking Voltage	$V_R$	45	Volts
Average Rectified Forward Current, $T_c \leq 125^\circ\text{C}$	$I_{F(ave)}$	75	Amps
derating, forward current, $T_c \geq 125^\circ\text{C}$	$dI_F/dT$	4	Amps/ $^\circ\text{C}$
Nonrepetitive Peak Surge Current, $t_p = 8.3$ ms, half-sinewave	$I_{FSM}$	500	Amps
Peak Repetitive Reverse Surge Current, $t_p = 1\mu\text{s}$ , $f = 1\text{kHz}$	$I_{RRM}$	2	Amp
Junction Temperature Range	$T_j$	-55 to +175	$^\circ\text{C}$
Storage Temperature Range	$T_{stg}$	-55 to +175	$^\circ\text{C}$
Thermal Resistance, Junction to Case:	$\theta_{JC}$	0.50 0.65	$^\circ\text{C/W}$
	MSASC75W45F MSASC75W45FR		

**Mechanical Outline**

**ThinKey™4**



# MSASC75W45F MSASC75W45FR

## Electrical Parameters

DESCRIPTION	SYMBOL	CONDITIONS	MIN	TYP.	MAX	UNIT
Reverse (Leakage)	IR <sub>25</sub>	VR= 45 Vdc, Tc= 25°C		100	750	uA
	IR <sub>125-1</sub>	VR= 12 Vdc, Tc= 125°C		1	-	mA
Current	IR <sub>125-2</sub>	VR= 36 Vdc, Tc= 125°C		2.5	-	mA
	IR <sub>125</sub>	VR= 45 Vdc, Tc= 125°C		4	50	mA
Forward Voltage pulse test, pw= 300 μs d/c≤ 2%	VF1	IF= 2 A, Tc= 25°C		435	-	mV
	VF2	IF= 10 A, Tc= 25°C		500	550	mV
	VF3	IF= 25 A, Tc= 25°C		550	625	mV
	VF4	IF= 50 A, Tc= 25°C		625	-	mV
	VF5	IF= 75 A, Tc= 25°C		685	760	mV
	VF6	IF= 100 A, Tc= 25°C		725	-	mV
	VF7	IF= 2 A, Tc= -55°C		550	-	mV
	VF8	IF= 10 A, Tc= -55°C		600	660	MV
	VF9	IF= 25 A, Tc= -55°C		630	700	MV
	VF10	IF= 50 A, Tc= -55°C		675	-	MV
	VF11	IF= 75 A, Tc= -55°C		715	800	mV
	VF12	IF= 2 A, Tc= 125°C		300	-	MV
	VF13	IF= 10 A, Tc= 125°C		385	440	MV
	VF14	IF= 25 A, Tc= 125°C		460	540	MV
	VF15	IF= 50 A, Tc= 125°C		540	-	MV
	VF16	IF= 75 A, Tc= 125°C		590	675	mV
	VF <sub>a</sub>	IF= 100 mA, Tc= 25°C		350	-	mV
VF <sub>b</sub>	IF= 100 mA, Tc= 125°C		200	-	mV	
VF <sub>c</sub>	IF= 100 mA, Tc= -55°C		485	-	mV	
Junction Capacitance	Cj1	VR= 10 Vdc		1900	-	pF
	Cj2	VR= 5 Vdc		2500	3000	pF
Breakdown Voltage	BVR	IR= 5 mA, Tc= 25°C		55		V
		IR= 5 mA, Tc= -55°C	45	47		V

